

Analytical Model for Atomic Relaxation in Twisted Moiré Materials

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By virtue of being atomically thin, the electronic properties of heterostructures built from two-dimensional materials are strongly influenced by atomic relaxation. The atomic layers behave as flexible membranes rather than rigid crystals. Here we develop an analytical theory of lattice relaxation in twisted moiré materials. We obtain analytical results for the lattice displacements and corresponding pseudo gauge fields, as a function of twist angle. We benchmark our results for twisted bilayer graphene and twisted WSe₂ bilayers using large-scale molecular dynamics simulations. Our theory is valid in graphene bilayers for twist angles $\theta \gtrsim 1^\circ$, and in twisted transition metal dichalcogenides for $\theta \gtrsim 4^\circ$. We also investigate how relaxation alters the electronic structure in twisted bilayer graphene, providing a simple extension to the continuum model to account for lattice relaxation.

Introduction — Since the first paper by dos Santos, Peres and Castro Neto [1], the community has been fascinated by the modification of the electronic properties of two-dimensional (2D) materials using twist angle [2, 3]. Twisted 2D materials have observable moiré patterns that depend on twist angle [4, 5], lattice symmetry [6, 7], and lattice mismatch [8]. These moiré patterns in turn strongly modify the electronic properties in ways that can be observed in STM [5, 9], transport [8, 10–13], and ARPES [14–17]. Following the seminal experimental observation of flat bands in 2018 [18], the field experienced a surge of exploration and discovery. There is now a large family of new artificial superlattices with tunable superlattice periods ~ 10 nm hosting a rich assortment of interacting electronic phenomena [19–35].

One wrinkle in the moiré story is that 2D atomic layers are not rigid, but flexible electronic membranes. This was known in early experimental studies [36, 37]. Theoretical treatments considering the electronic and mechanical properties on equal footing soon followed [38–40]. At small twist angles, small atomic displacements from the rigid twisted configuration give large gains in the electronic potential energy at a small cost in elastic energy. Since lattice relaxation is expected to strongly modify the electronic structure, the original claims of flat bands [41] were met with some skepticism. It was only after the experimental observations that relaxation effects were considered in magic angle twisted bilayer graphene (TBG). As expected, relaxation effects strongly modify the electronic structure. Remarkably, relaxation actually further flattens and isolates the lowest energy moiré bands [42–44] confirming that atomic relaxation is an important ingredient to understand the observed superconductivity and correlated insulator states.

In this Letter we propose a symmetry-based and fully analytical physically motivated theory for atomic relaxation. By benchmarking our results with LAMMPS molecular dynamics simulations (involving numerical calculations with more than 4 million atoms), we show that our theory is valid for a wide range of twist angles for both twisted graphene, including at the magic angle, and parallel stacked transition metal dichalcogenides (TMD) homobilayers i.e. where corresponding atoms in two layers are aligned. This enables us to propose an effective electronic model for twisted bilayer graphene that fully captures the effects of lattice relaxation on observables including band width, Fermi velocity and pseudomagnetic fields. We note that the success of the original rigid model [1, 41] was largely due to its conceptual clarity and computational simplicity making it broadly accessible. Our simple analytic extension to this model to account for atomic relaxation retains all of these advantages.

The importance of lattice reconstruction is determined by the dimensionless quantity $V_1/[\mu \sin^2(\theta/2)]$, where V_1 is the van der Waals energy scale and μ is a Lamé elastic coefficient [42]. Using accepted values [45, 46], we anticipate that relaxation will be an order-of-magnitude stronger in twisted TMDs compared to TBG; since lattice relaxation effects are expected to be important for $\theta < 1^\circ$ in TBG, we expect it to be important at even larger angles for twisted TMDs. Previous studies of lattice relaxation have relied on elasticity theory [38, 42], DFT-parametrized effective models [43], or large-scale classical atomic molecular dynamics calculations [44]. Here we provide a largely analytical approach which is fully consistent with prior numerical works over a wide range of the parameter space and provides both additional insights and a flexible method for treating relaxation effects.

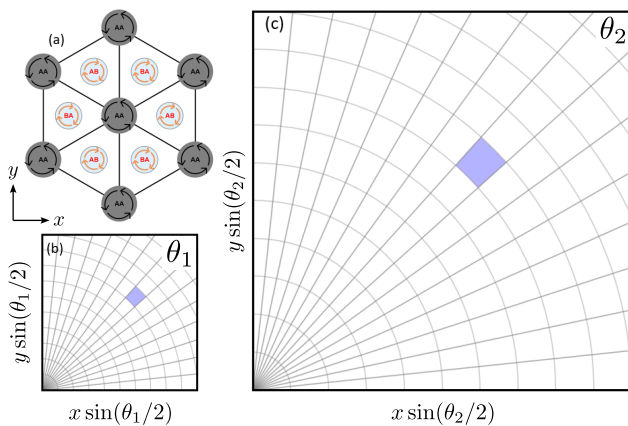


FIG. 1. Illustration of the analytical model for lattice relaxation in twisted moirés. (a) Lattice relaxation prompts neighborhoods of energetically favorable stacking domains to counter-rotate against external twisting, to locally restore the favorable stacking. Simultaneously, atoms in unfavorable domains co-rotate with the twist. This suggests that $\nabla \cdot \mathbf{u} = 0$ where $\mathbf{u}(\mathbf{r})$ is the in-plane displacement field. (b, c) Conformal map between different moiré cells. While coordinates scale as $1/\sin(\theta/2)$, the displacement field, proportional to the van der Waals force in a small area, scales as $1/\sin^2(\theta/2)$.

Analytical Model — We begin by considering atomic relaxation in twisted bilayer graphene (TBG) and extend our results to other twisted homobilayers later. Without relaxation, the geometry of TBG is obtained by starting from a fixed stacking (e.g., AA stacking) and introducing a relative twist angle θ between the layers. This results in the rigid configuration of the twisted system [47]. However, the two-dimensional atomic sheets act more like elastic membranes, gaining energy by allowing atoms to adjust their positions. The relaxed atomic positions of the top and bottom layers can be written as $\mathbf{r} \pm [\mathbf{u}(\mathbf{r}) + h(\mathbf{r})\hat{z}]$, respectively, where \mathbf{r} are the rigid in-plane coordinates, and $\mathbf{u}(\mathbf{r})$ and $h(\mathbf{r})$ are the relative in-plane and out-of-plane displacement fields due to lattice relaxation, respectively. As discussed in the Supplemental Material (SM) [48], for the angles we consider, contributions from in-plane homostain and buckling are negligible.

We first approach the relaxation problem with a hypothesis based on physical intuition, and then confirm it with a symmetry analysis. The relative rotation of the layers induces variation in the local stacking registry, forming a triangular pattern of high-symmetry stacking points, as shown in Fig. 1(a). The AB and BA regions are degenerate energy minima, whereas the AA regions are energy maxima [49]. The AB and BA regions maintain their low-energy configuration by resisting rigid rotation and tend to locally counter-rotate against the rigid rotation between the layers. Conversely, to decrease their energy, the AA regions tend to rotate further in the same direction, resulting in an additional local rotation on top

m	g/g_1	α_m	β_m	h_m
1	1	\mathbb{R}	0	\mathbb{R}
2	$\sqrt{3}$	\mathbb{R}	0	\mathbb{R}
3	2	\mathbb{R}	0	\mathbb{R}
4, 5	$\sqrt{7}$	\mathbb{R}	\mathbb{R}	\mathbb{R}

TABLE I. Allowed values of the in-plane (α_m and β_m) and out-of-plane (h_m) Fourier components of the displacement fields, for D_6 symmetry for the first five moiré shells indexed by m with $g_1 = 4\pi/\sqrt{3}L$.

of the rigid rotation, as illustrated in Fig. 1(a). This gives rise to a triangular lattice of vortices in \mathbf{u} , with opposite vorticity at the AB and BA regions compared to the AA regions. This physical picture leads us to hypothesize that lattice relaxation will be primarily rotational, resulting in an incompressible (solenoidal) displacement field:

$$\nabla \cdot \mathbf{u}(\mathbf{r}) = 0. \quad (1)$$

We now show that symmetries require that Eq. (1) is an exact constraint for sufficiently smooth relaxation patterns. Since the rigid configuration is adiabatically connected to the relaxed one, the displacement field $\mathbf{u}(\mathbf{r})$ should obey the same symmetries of the moiré and vary slowly on the atomic scale. Hence it can be expanded as

$$\mathbf{u}(\mathbf{r}) = \sum_{\mathbf{g}} \mathbf{u}_{\mathbf{g}} e^{i\mathbf{g} \cdot \mathbf{r}}, \quad (2)$$

where the sum runs over moiré reciprocal vectors and $\mathbf{u}_{\mathbf{g}}$ are in-plane Fourier components. A Helmholtz decomposition in terms of transverse and longitudinal parts gives

$$\mathbf{u}_{\mathbf{g}} = \frac{a}{L} \frac{\alpha_{\mathbf{g}} \hat{z} \times \mathbf{g} + \beta_{\mathbf{g}} \mathbf{g}}{ig^2}, \quad (3)$$

where the $\alpha_{\mathbf{g}}$ ($\beta_{\mathbf{g}}$) are dimensionless and correspond to rotational (volumetric) displacements, a is the lattice constant of graphene, and L is the moiré lattice constant. While these coefficients are *a priori* unknown, they are constrained by symmetry. For example, an in-plane symmetry \mathcal{S} requires that $\mathcal{S}\mathbf{u}(\mathbf{r}) = \mathbf{u}(\mathcal{S}\mathbf{r})$ giving $\alpha_{\mathcal{S}\mathbf{g}} = \det(\mathcal{S})\alpha_{\mathbf{g}}$ and $\beta_{\mathcal{S}\mathbf{g}} = \beta_{\mathbf{g}}$. Taking into account the emergent D_6 symmetry of the moiré, we find constraints on the α_m and β_m where m labels shells of moiré reciprocal vectors, defined as being closed under C_{6z} rotations [48]. The allowed values for the first five shells are shown in Table I. Importantly, we find that the D_6 symmetry strongly suppresses volumetric contributions, which in fact vanish up to the third shell of moiré reciprocal vectors. Restricting to the first shell, we obtain

$$\mathbf{u}(\mathbf{r}) = \alpha \frac{\sqrt{3}a}{2\pi} \sum_{i=1}^3 \hat{z} \times \hat{g}_i \sin(\mathbf{g}_i \cdot \mathbf{r}), \quad (4)$$

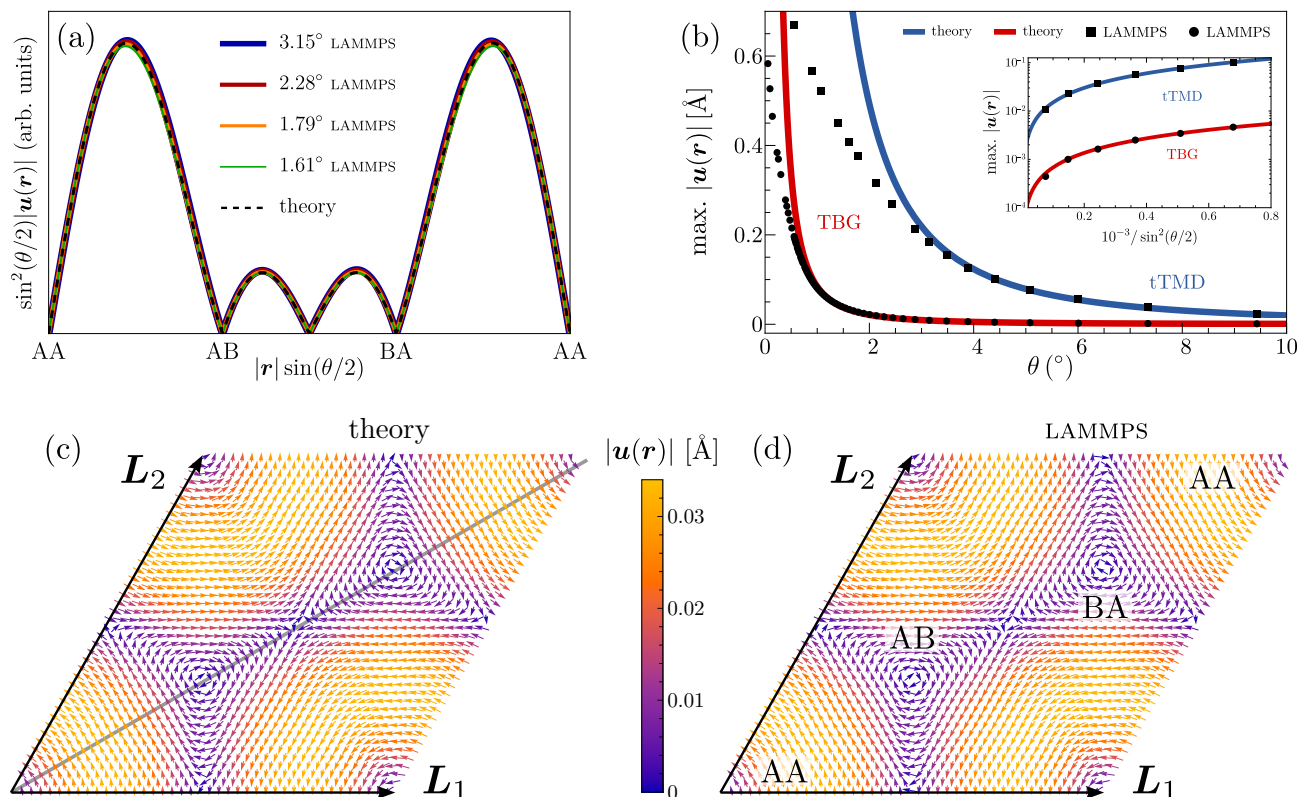


FIG. 2. Validation of theory. (a) Magnitude of the in-plane displacement field $\mathbf{u}(\mathbf{r})$ due to lattice relaxation along the diagonal line in panel (c) for different twist angles in TBG. The coordinate is scaled by the moiré period while the displacement is scaled by the moiré cell area. Both LAMMPS data (solid lines) and theory (dashed line) collapse to the same curve after scaling. (b) Maximum value of $|\mathbf{u}(\mathbf{r})|$ as a function of twist angle, comparing LAMMPS to theory for twisted bilayer graphene and twisted bilayer WSe₂ near parallel stacking. (c) In-plane displacement field of the top TBG layer calculated with Eq. (4) for a twist angle $\theta = 1.61^\circ$. (d) In-plane displacement field computed with LAMMPS for the same twist angle as (c).

where the sum runs over three reciprocal vectors of the first shell related by C_{3z} rotations. Equation (4) is one of the main results of our paper. It gives an analytical expression for $\mathbf{u}(\mathbf{r})$ that contains only a single dimensionless parameter α which can be determined either from theory and simulations (as we do below), or experiment.

Next we investigate $\alpha(\theta)$. In Fig. 1 we observe that the geometry of moiré cells corresponding to different twist angles can be mapped: a point \mathbf{r}_1 in a moiré cell (θ_1) is mapped to \mathbf{r}_2 in another moiré cell (θ_2) with identical local environments, according to $\mathbf{r}_1 \sin(\theta_1/2) = \mathbf{r}_2 \sin(\theta_2/2)$. Thus the coordinates scale as $1/\sin(\theta/2)$. Likewise, we can map areas between different moirés. If we assume that the van der Waals interaction varies slowly on the atomic scale, the net force in an area patch scales as $1/\sin^2(\theta/2)$. For small displacements, the displacement field is proportional to the force giving

$$\sin^2\left(\frac{\theta_1}{2}\right) \mathbf{u}_1\left(\mathbf{r}/\sin\frac{\theta_1}{2}\right) = \sin^2\left(\frac{\theta_2}{2}\right) \mathbf{u}_2\left(\mathbf{r}/\sin\frac{\theta_2}{2}\right), \quad (5)$$

which implies that $\alpha(\theta) = c/[4\sin^2(\theta/2)]$ where c is a materials constant and the factor of 4 has been added for convenience. Using elastic theory, with the *ansatz* from Eq. (4), we find $c = V_1/\mu$ [48].

An immediate consequence is that the displacement field divided by the moiré cell area as a function of \mathbf{r}/L should be independent of twist angle. We test this collapse using LAMMPS molecular dynamics simulations, as shown in Fig. 2(a). Beyond the collapse of the numerical data for different twist angles, we find excellent agreement with the model [dashed line in Fig. 2(a)]. Next, we use the LAMMPS data to fix c , the single material-dependent parameter of the theory. By fitting the data for large twist angles, as shown in Fig. 2(b), we find $c_{\text{TBG}} \approx 2.2 \times 10^{-5}$ for TBG and $c_{\text{tWSe}_2} \approx 3.9 \times 10^{-4}$ for parallel stacked bilayer WSe₂ (since TMDs lack C_{2z} symmetry, one has to distinguish between rotating away from parallel and antiparallel stacking). As anticipated, we find $c_{\text{tWSe}_2} \gg c_{\text{TBG}}$ since TMDs are both elastically softer and have larger stacking-fault energies. Interestingly, even though moirés of twisted homobilayer TMDs only have D_3 symmetry, the stacking-fault energy for parallel stacking effectively has D_6 symmetry as a function of atomic registry [50]. Such an emergent symmetry is a generic feature of moiré materials [51] and explains why our theory works well for both TBG and parallel-stacked homobilayer tTMDs.

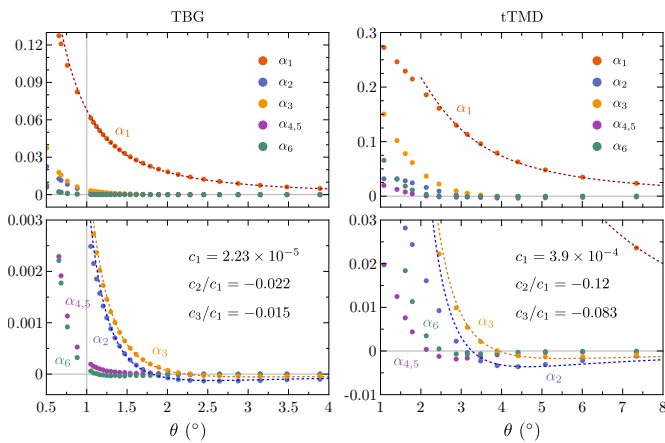


FIG. 3. Rotational Fourier components α_m of the in-plane displacement field $\mathbf{u}(\mathbf{r})$ for different shells m as a function of twist angle for (a) TBG and (b) twisted parallel-stacked WSe₂ where $\mathbf{u}(\mathbf{r})$ is obtained from the W atoms. Dashed lines fit the expressions for α_1 , α_2 , and α_3 with fit parameters indicated.

Having fixed the parameter c with LAMMPS, we now compare the full profile $\mathbf{u}(\mathbf{r})$ between theory and simulations for TBG. This is shown for $\theta = 1.61^\circ$ in Fig. 2(c) and (d). We see that the displacement fields are nearly identical. Remarkably, for TBG the theory is valid for $\theta \gtrsim 1^\circ$ and works even at the magic angle. For tTMDs, on the other hand, lattice relaxation is more significant, giving larger displacements for the same twist angle, and our model works for $\theta \gtrsim 4^\circ$. For example, the displacements for tWSe₂ near 4° have similar magnitudes as those for TBG near 1° , see Fig. 2(b). As the twist angle decreases below these values, the theory starts to deviate from LAMMPS. We attribute this breakdown in simple scaling to nonlinear contributions to the van der Waals energy. Indeed, we calculate these corrections by minimizing the total energy $U[\mathbf{u}(\mathbf{r})] = U_{\text{elastic}} + U_{\text{vdW}}$ subject to D_6 symmetry. To second order, we find there are only rotational components for the first three shells

$$\alpha_1 \simeq \frac{c_1}{4 \sin^2 \frac{\theta}{2}} - \frac{c_1^2}{16 \sin^4 \frac{\theta}{2}}, \quad (6)$$

$$\alpha_{2,3} \simeq \frac{c_{2,3}}{4 \sin^2 \frac{\theta}{2}} + \frac{c_1^2}{16 \sin^4 \frac{\theta}{2}}, \quad (7)$$

with $c_i = V_i/\mu$. Here $c_1 = c$ is the parameter we introduced before, while c_2 and c_3 correspond to 2nd and 3rd shell corrections to the stacking-fault energy. The resulting parameters obtained by fitting to LAMMPS are shown in Fig. 3. Our results are similar to the ratios $V_{2,3}/V_1$ obtained from the stacking-fault energy calculated with DFT calculations [50]. Using this framework, which only assumes that out-of-plane displacements are small compared to in-plane ones, we generalize this result by calcu-

lating the energy in lowest order of $|\mathbf{u}|/a$ to find

$$U \sim \frac{a^2}{L^2} \sum_{\mathbf{g}} [\mu |\alpha_{\mathbf{g}}|^2 + (\lambda + 2\mu) |\beta_{\mathbf{g}}|^2] - 2 \sum_{\mathbf{g}} V_{\mathbf{g}} \alpha_{-\mathbf{g}}, \quad (8)$$

where μ and λ are Lamé parameters and $V_{\mathbf{g}}$ are Fourier components of the stacking-fault energy. The energy is minimized by $\alpha_{\mathbf{g}} = L^2 V_{\mathbf{g}} / \mu a^2$ and $\beta_{\mathbf{g}} = 0$. Hence, the in-plane displacement field to lowest order is purely rotational in *twisted* moiré materials regardless of commensuration or symmetry constraints consistent with experimental observations [52]. As discussed earlier, symmetry can further suppress volumetric terms which is shown explicitly for D_6 in Table I.

Effective Relaxed Electronic Model — Armed with the analytical theory for $\mathbf{u}(\mathbf{r})$, we can now incorporate relaxation into a continuum model for the low-energy bands of TBG [41]. In the continuum model, the low-energy Dirac fermions of the two graphene layers are coupled by an interlayer moiré potential that is expanded in successive harmonics [48]. Close to the magic angle, we find that the moiré potential is dominated by the first harmonic. We propose a continuum model valid for $\theta \gtrsim 1^\circ$ with a modified interlayer moiré coupling,

$$T(\mathbf{r}) = \sum_{j=1}^3 T_j e^{i\mathbf{q}_j \cdot \mathbf{r}}, \quad (9)$$

where $T_j = e^{-i(j-1)\pi\sigma_z/3} (w_1 e^{i\phi\sigma_z} + w_2 \sigma_x) e^{i(j-1)\pi\sigma_z/3}$ with $\sigma_{x,y,z}$ Pauli matrices, and \mathbf{q}_i are moiré tunnelling vectors. Here w_1 and w_2 are tunnelling amplitudes between equal and opposite sublattices, respectively. We introduce a new symmetry allowed parameter ϕ (also considered recently in Ref. [53]) that encodes information about the lattice relaxation [48]. In the absence of relaxation, within a two-center approximation, $w_1 = w_2$ and $\phi = 0$ and only one moiré shell is necessary [1, 41, 47]. In this case, there is no energy gap between the flat bands and remote dispersive bands. Including relaxation, not only is $w_1 \neq w_2$, and the gap becomes finite [42, 54], but higher-order shells as well as nonlocal moiré terms become important. For this paper, we keep only one shell, encoding the information of higher shells in ϕ . The resulting electronic spectrum (see Sec. S5 B in [48]) matches large-scale relaxed tight-binding calculations [55, 56].

Perturbatively, one can show that $\theta_{\text{magic}} \propto w_2 a / \hbar v_F$ where the magic angle is defined by vanishing Fermi velocity [41, 48]. Since w_2 increases with relaxation [43], the magic angle increases. However, relaxation induces strain giving rise to a pseudomagnetic field [57] which we find can be as large as ~ 10 T near 1° . The displacement field in Eq. (4) yields a pseudo vector potential $\pm \mathbf{A}(\mathbf{r})$ for top and bottom layer, respectively. Here $\mathbf{A}(\mathbf{r}) = [2\gamma(\theta)/ev_F] \sum_{i=1}^3 \hat{z} \times \hat{g}_i \cos(\mathbf{g}_i \cdot \mathbf{r})$ where $\gamma = \sqrt{3} \hbar v_F L / 4\pi \ell_0^2$ with $\ell_0 \sim 15$ nm the effective magnetic length [48]. Importantly, the pseudomagnetic field

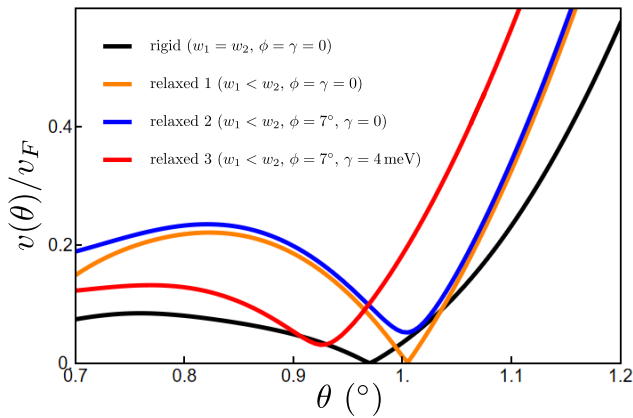


FIG. 4. Modification of Fermi velocity $v(\theta)$ due to lattice relaxation in TBG. The black curves corresponds to the rigid continuum model with $w_1 = w_2$ and $\phi = 0$. Taking into account relaxation, we consider $w_1 \neq w_2$ with $\phi = 0$ (orange) and finite ϕ (blue) where ϕ is the AA tunneling phase. This modification results in a finite minimum value for the Fermi velocity at the nominal magic angle. Finally, the red curve also incorporates the pseudo magnetic field that also shifts the value of the magic angle.

reduces the magic angle [48] such that overall the magic angle does not change much. By contrast, the phase ϕ makes the Fermi velocity attain only a finite minimum value as seen in Fig. 4 where Dirac point velocity versus twist angle is shown for different cases. Close to magic angle $w_2 = 97$ meV, $w_1 = 79$ meV, and $\gamma = 4$ meV [48].

Conclusion — The field of moiré materials is rapidly expanding, and there is a need for transparent and physically motivated models to understand and interpret the large influx of experimental data. In this work, we have proposed an analytical atomic relaxation model for twisted moiré materials. We have benchmarked our model against large-scale molecular dynamics showing remarkable agreement. The model has several important consequences including the emergence of large pseudo-magnetic fields and the shift of the magic angle. The generality of our formalism implies that it could be used to study other twisted 2D materials where relaxation effects are even more important than in twisted bilayer graphene.

Note added — During the preparation of this manuscript, Ceferino and Guinea submitted a preprint [58] with a similar model for relaxed twisted bilayer and trilayer graphene. Unlike our work, they do not benchmark their results with large-scale molecular dynamics simulations, and they do not generalize to other moiré materials, or explore the range of validity of the theory.

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Supplemental Material

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S1. DISPLACEMENT FIELDS FROM SYMMETRY

In this section, we constrain the displacement fields due to relaxation in twisted bilayer graphene (TBG) using the symmetry of the moiré lattice. In particular, we consider commensurate approximants with the twist center at a graphene hexagon center that have the periodicity of the moiré lattice. These structures have point group $D_6 = \langle \mathcal{C}_{6z}, \mathcal{C}_{2x} \rangle$ where \mathcal{C}_{6z} is a rotation by $\pi/3$ about the z axis and \mathcal{C}_{2x} is a π rotation about the x axis [59], as illustrated in Fig. S1(a). The corresponding commensurate twist angles are given by [47]

$$\cos \theta_{mr} = \frac{3m^2 + 3mr + r^2/2}{3m^2 + 3mr + r^2}, \quad (\text{S1})$$

with $r = 1$. The displacements fields are defined through the atomic positions

$$\mathbf{r}_t = \mathbf{r}_+ + \mathbf{u}_t(\mathbf{r}_+) + h_t(\mathbf{r}_+)\hat{z}, \quad (\text{S2})$$

$$\mathbf{r}_b = \mathbf{r}_- + \mathbf{u}_b(\mathbf{r}_-) + h_b(\mathbf{r}_-)\hat{z}, \quad (\text{S3})$$

with $\mathbf{r}_\pm = R_{\pm\theta/2}\mathbf{r}$ where $\mathbf{r} = n_1\mathbf{a}_1 + n_2\mathbf{a}_2 + \boldsymbol{\delta}$ are the atomic positions of monolayer graphene with $n_1, n_2 \in \mathbb{Z}$ and $\boldsymbol{\delta}$ the sublattice position in the graphene cell. Here the origin is placed at a hexagon center and $R_{\pm\theta/2}$ is the rotation matrix for a counterclockwise rotation about the

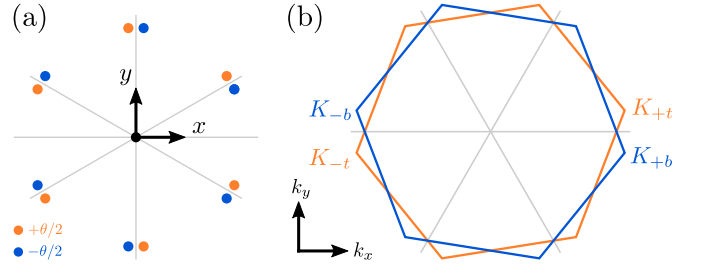


FIG. S1. (a) Twisted bilayer graphene with D_6 symmetry showing only carbon atoms closest to the twist center (black dot). Symmetry axes are shown in gray. (b) Corresponding momentum space of the two rotated layers.

z axis by an angle $\pm\theta/2$. In the absence of lattice relaxation, i.e., the rigid twisted configuration, the in-plane displacement fields $\mathbf{u}_{t/b}$ vanish and $h_{t/b}(\mathbf{r}) = \pm h_0/2$ is constant. We further define the displacement fields

$$\mathbf{u}_{t/b}(\mathbf{r}) = \bar{\mathbf{u}}(\mathbf{r}) \pm \mathbf{u}(\mathbf{r}), \quad (\text{S4})$$

$$h_{t/b}(\mathbf{r}) = \bar{h}(\mathbf{r}) \pm h(\mathbf{r}), \quad (\text{S5})$$

since both the homo ($\bar{\mathbf{u}}$ and \bar{h}) and hetero (\mathbf{u} and h) displacements are symmetry-allowed and transform properly under D_6 . Physically, \bar{h} corresponds to buckling of the graphene sheets while h is a breathing mode. To keep

the discussion succinct, we focus on the relative displacements $\mathbf{u}(\mathbf{r})$ and $h(\mathbf{r})$ and only give the final results for $\bar{\mathbf{u}}(\mathbf{r})$ and $\bar{h}(\mathbf{r})$. Assuming the moiré periodicity is preserved after lattice relaxation, we can write

$$\mathbf{u}(\mathbf{r}) = \sum_{\mathbf{g}} \mathbf{u}_{\mathbf{g}} e^{i\mathbf{g}\cdot\mathbf{r}}, \quad (\text{S6})$$

$$h(\mathbf{r}) = \sum_{\mathbf{g}} h_{\mathbf{g}} e^{i\mathbf{g}\cdot\mathbf{r}}, \quad (\text{S7})$$

where \mathbf{g} are moiré reciprocal vectors and $h_{\mathbf{g}} = h_{-\mathbf{g}}^*$ and $\mathbf{u}_{\mathbf{g}} = \mathbf{u}_{-\mathbf{g}}^*$ are complex Fourier components. We now write the in-plane components in terms of their Helmholtz decomposition,

$$\mathbf{u}_{\mathbf{g}} = \frac{a}{L} \frac{\alpha_{\mathbf{g}} \hat{z} \times \mathbf{g} + \beta_{\mathbf{g}} \mathbf{g}}{ig^2}, \quad (\text{S8})$$

for $g = |\mathbf{g}| \neq 0$ and where $\alpha_{\mathbf{g}} = \alpha_{-\mathbf{g}}^*$ and $\beta_{\mathbf{g}} = \beta_{-\mathbf{g}}^*$ are complex numbers. Note that \mathbf{u}_0 is a constant relative shift between layers which does not affect the long-wavelength physics for small twists. Moreover, these coefficients are related to the divergence and curl:

$$\nabla \times \mathbf{u} = \sum_{\mathbf{g}} i\mathbf{g} \times \mathbf{u}_{\mathbf{g}} e^{i\mathbf{g}\cdot\mathbf{r}} = \frac{\hat{z}a}{L} \sum_{\mathbf{g}} \alpha_{\mathbf{g}} e^{i\mathbf{g}\cdot\mathbf{r}}, \quad (\text{S9})$$

$$\nabla \cdot \mathbf{u} = \sum_{\mathbf{g}} i\mathbf{g} \cdot \mathbf{u}_{\mathbf{g}} e^{i\mathbf{g}\cdot\mathbf{r}} = \frac{a}{L} \sum_{\mathbf{g}} \beta_{\mathbf{g}} e^{i\mathbf{g}\cdot\mathbf{r}}, \quad (\text{S10})$$

which give the rotational and in-plane volumetric components of the displacement gradient.

We now show how the displacement fields are constrained by symmetry. Under an in-plane symmetry \mathcal{S} , an in-plane vector field and a scalar function that preserve the symmetry have to transform as

$$\mathbf{u}(\mathcal{S}\mathbf{r}) = \mathcal{S}\mathbf{u}(\mathbf{r}), \quad (\text{S11})$$

$$h(\mathcal{S}\mathbf{r}) = h(\mathbf{r}), \quad (\text{S12})$$

and similarly in reciprocal space,

$$\mathbf{u}_{\mathcal{S}\mathbf{g}} = \mathcal{S}\mathbf{u}_{\mathbf{g}}, \quad (\text{S13})$$

$$h_{\mathcal{S}\mathbf{g}} = h_{\mathbf{g}}. \quad (\text{S14})$$

From Eq. (S8) we then see that $\alpha_{\mathbf{g}}$ ($\beta_{\mathbf{g}}$) transforms as a pseudoscalar (scalar) under in-plane symmetries,

$$\alpha_{\mathcal{S}\mathbf{g}} = \det(\mathcal{S})\alpha_{\mathbf{g}}, \quad \beta_{\mathcal{S}\mathbf{g}} = \beta_{\mathbf{g}}. \quad (\text{S15})$$

On the other hand, for a symmetry that flips the layers, such as \mathcal{C}_{2x} rotation symmetry, we have

$$\mathbf{u}(x, y) = \begin{pmatrix} -1 & 0 \\ 0 & 1 \end{pmatrix} \mathbf{u}(x, -y), \quad (\text{S16})$$

$$h(x, y) = h(x, -y), \quad (\text{S17})$$

since $\mathbf{u}_t(x, y) \mapsto \text{diag}(1, -1)\mathbf{u}_b(x, -y)$ and $h_t(x, y) \mapsto -h_b(x, -y)$ under \mathcal{C}_{2x} . To proceed, we first organize the

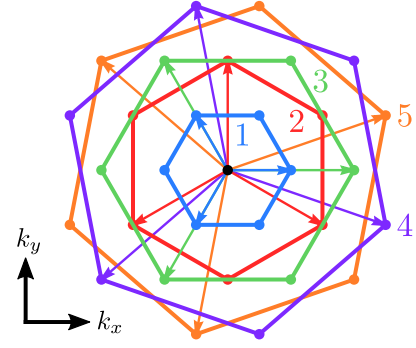


FIG. S2. First five shells of reciprocal lattice vectors of the triangular lattice.

m	α_m	β_m	h_m	m	$\bar{\alpha}_m$	$\bar{\beta}_m$	\bar{h}_m
1	\mathbb{R}	0	\mathbb{R}	1	0	\mathbb{R}	0
2	\mathbb{R}	0	\mathbb{R}	2	0	\mathbb{R}	0
3	\mathbb{R}	0	\mathbb{R}	3	0	\mathbb{R}	0
4	\mathbb{R}	\mathbb{R}	\mathbb{R}	4	\mathbb{R}	\mathbb{R}	\mathbb{R}
5	α_4	$-\beta_4$	h_4	5	$-\bar{\alpha}_4$	$\bar{\beta}_4$	$-\bar{h}_4$

TABLE I. Symmetry-allowed values for the in-plane and out-of-plane Fourier coefficients of the displacement fields in the presence of D_6 symmetry for the first five reciprocal shells.

reciprocal vectors of the triangular Bravais lattice in different shells, where each shell has constant $|\mathbf{g}|$ and is invariant under \mathcal{C}_{6z} . For example, the first shell is given by the six reciprocal vectors with $|\mathbf{g}| = 4\pi/\sqrt{3}L$. An illustration up to the fifth shell is shown in Fig. S2.

We now discuss how the two generators of D_6 constrain the Fourier components. First, we see that \mathcal{C}_{6z} rotation symmetry together with the reality of the displacements requires that each shell is characterized by a single real Fourier coefficient which we call α_m , β_m , and h_m where $m = 1, 2, \dots$ labels the shells. Second, \mathcal{C}_{2x} symmetry requires that $\beta_{g_x, g_y} = -\beta_{g_x, -g_y}$ while $\alpha_{g_x, g_y} = \alpha_{g_x, -g_y}$ and $h_{g_x, -g_y} = h_{g_x, g_y}$. Hence, we find that the volumetric components of the first three shells vanish. For the degenerate fourth and fifth shell, we further find $\alpha_4 = \alpha_5$, $\beta_4 = -\beta_5$, and $h_4 = h_5$. Hence D_6 symmetry does not forbid but suppresses in-plane volumetric components.

In conclusion, up to the fifth shell, there are four real rotational coefficients α_1 , α_2 , α_3 , and $\alpha_4 = \alpha_5$, as well as one in-plane volumetric coefficient $\beta_4 = -\beta_5$, and four real out-of plane coefficients h_1 , h_2 , h_3 , and $h_4 = h_5$. An overview of the symmetry-allowed parameters up to the fifth shell is given in Table I for both the homo and hetero displacements.

S2. BEYOND THE FIRST-SHELL APPROXIMATION

In the main text, we used the first-shell approximation to find a minimal model for lattice relaxation in TBG, which works well for twist angles $\theta \gtrsim 1^\circ$. Here, we address corrections due to more distant shells.

We start by taking the discrete Fourier transform of the LAMMPS data. This yields the coefficients α_m , β_m , and h_m that were defined in Section S1. Results for the rotational coefficients α_m of the relative displacement are shown up to the sixth shell in Fig. 3 of the main text. We do not show the volumetric in-plane components β_m , nor do we show the coefficients $\bar{\alpha}_m$ and $\bar{\beta}_m$ that are related to homostain, as these are at least two orders of magnitude smaller than α_m . The out-of-plane

components are discussed below. We start by giving a simple theory for the rotational coefficients α_1 , α_2 , and α_3 .

A. Elastic theory

We estimate the symmetry-allowed Fourier coefficients of the displacement fields for the regime $\theta \gtrsim 1^\circ$ up to the third shell. To this end, we use a linear and isotropic elastic theory to model the intralayer strain and we use the local-stacking approximation to model the interlayer van der Waals interactions. In particular, we minimize the energy functional $U = U_{\text{elastic}} + U_{\text{vdW}}$ given an *ansatz* for the displacement fields that is motivated by symmetry and the LAMMPS molecular dynamics simulations. The elastic and stacking-fault energy are given by [42, 50, 58]

$$U_{\text{elastic}}[\partial_i \mathbf{u}, \partial_i \bar{\mathbf{u}}, \partial_i h, \partial_i^2 h, \partial_i \bar{h}, \partial_i^2 \bar{h}] = \sum_{l=t,b} \int_{\text{cell}} d^2 \mathbf{r} \left\{ \frac{\lambda}{2} \left[\text{tr} \left(\frac{u_l + u_l^t}{2} \right) \right]^2 + \mu \text{tr} \left(\frac{u_l + u_l^t}{2} \right)^2 + \frac{\kappa}{2} (\nabla^2 h_l)^2 \right\}, \quad (\text{S18})$$

$$U_{\text{vdW}}[\mathbf{u}(\mathbf{r})] = \sum_{\mathbf{g}} V_{\mathbf{g}} \int_{\text{cell}} d^2 \mathbf{r} \exp \left\{ i \left[\mathbf{g} \cdot \mathbf{r} + \frac{2L}{a} \hat{z} \times \mathbf{g} \cdot \mathbf{u}(\mathbf{r}) \right] \right\}, \quad (\text{S19})$$

where u_l is the displacement gradient for layer $l = t, b$, $V_{\mathbf{g}}$ are Fourier components of the stacking-fault energy, and $(L/a)\hat{z} \times \mathbf{g}$ is a reciprocal lattice vector of monolayer graphene. If we now assume that there is only a relative displacement between layers, we have $\mathbf{u}_{t/b} = \pm \mathbf{u}$ and $h_{t/b} = \pm h$ such that

$$(u_{t/b})_{ij} = \pm \frac{\partial u_i}{\partial r_j} + \frac{1}{2} \frac{\partial h}{\partial r_i} \frac{\partial h}{\partial r_j}, \quad (\text{S20})$$

respectively. In this case, one finds that the in-plane motion becomes decoupled from the out-of-plane motion in U_{elastic} . This immediately yields a trivial solution for the out-of-plane displacement field $h = \text{constant}$. Note

that this theory lacks information on the preferred height profile of the twisted bilayer system. In principle, this would modify U_{vdW} , coupling the in-plane and out-of-plane displacements [60]. However, we assume here that the height profile follows the optimal value given by the local stacking, which agrees well with the LAMMPS simulations for twist angles $\theta \gtrsim 1^\circ$. As a side note, if one neglects out-of-plane displacements then the homo and hetero displacements are decoupled: $U_{\text{elastic}}[\partial_i \mathbf{u}, \partial_i \bar{\mathbf{u}}] = 2U_{\text{elastic}}[\partial_i \mathbf{u}] + 2U_{\text{elastic}}[\partial_i \bar{\mathbf{u}}]$ such that $\bar{\mathbf{u}}$ vanishes.

We now further assume that the displacements are small such that $|\mathbf{u}| \ll a$. Then we can expand the van der Waals energy density in powers of $|\mathbf{b}_i \cdot \mathbf{u}|$. This yields

$$U_{\text{vdW}} = \sum_{\mathbf{g}} V_{\mathbf{g}} \int d^2 \mathbf{r} e^{i\mathbf{g} \cdot \mathbf{r}} \left\{ 1 + \frac{2iL}{a} \hat{z} \times \mathbf{g} \cdot \mathbf{u}(\mathbf{r}) - \frac{1}{2} \left[\frac{2L}{a} \hat{z} \times \mathbf{g} \cdot \mathbf{u}(\mathbf{r}) \right]^2 + \dots \right\} \quad (\text{S21})$$

$$= A \sum_{\mathbf{g}} V_{\mathbf{g}} \left(\delta_{\mathbf{g},0} - 2\alpha_{-\mathbf{g}} - \frac{2L^2}{a^2} \sum_{\mathbf{g}' \neq \mathbf{g}} (\hat{z} \times \mathbf{g} \cdot \mathbf{u}_{-\mathbf{g}'}) (\hat{z} \times \mathbf{g} \cdot \mathbf{u}_{\mathbf{g}'-\mathbf{g}}) + \dots \right) \quad (\text{S22})$$

$$= AV_0 - 2A \sum_{\mathbf{g}} V_{\mathbf{g}} \alpha_{-\mathbf{g}} + \mathcal{O}(|\mathbf{u}|^2/a^2), \quad (\text{S23})$$

where $A = \sqrt{3}L^2/2$ is the moiré cell area and we used

Eq. (S8). We therefore find that in lowest order, the

stacking-fault energy only contains contributions from the rotational components of the in-plane displacement field. This feature is universal for *twisted* moiré materials and can be traced back to the fact to the local disregistry of the atoms,

$$\mathbf{d}(\mathbf{r}) = 2 \sin(\theta/2) \hat{z} \times \mathbf{r} + 2\mathbf{u}(\mathbf{r}). \quad (\text{S24})$$

To proceed, we expand the in-plane displacement field up to the third shell of reciprocal vectors. We also know from our symmetry analysis that D_6 forbids $\nabla \cdot \mathbf{u}$ up to the third shell, giving three rotational coefficients α_1 , α_2 , and α_3 to be determined. Under these approximations, that are justified by the molecular dynamics simulation,

$$U_{\text{elastic}} = \mu \int d^2\mathbf{r} \left[(u_{xx} - u_{yy})^2 + (u_{xy} + u_{yx})^2 \right] \quad (\text{S25})$$

$$= \frac{6Aa^2\mu}{L^2} (\alpha_1^2 + \alpha_2^2 + \alpha_3^2). \quad (\text{S26})$$

Next, we expand the integrand of U_{vdW} . We only consider the first three shells of $V_{\mathbf{g}}$ [50]. Moreover, since the stacking-fault energy for TBG and homobilayer tTMDs near parallel stacking has D_6 symmetry, the coefficients V_1 , V_2 , and V_3 need to be real. Expanding α_1 , α_2 , and α_3 up to second order yields

$$\begin{aligned} U_{\text{vdW}} \simeq 6A \left\{ V_1 \alpha_1 [\alpha_1 - 2(1 + \alpha_2 + \alpha_3)] \right. \\ \left. + V_2 [9\alpha_1^2 + \alpha_2(\alpha_2 - 2)] \right. \\ \left. + V_3 [8\alpha_1(\alpha_1 + \alpha_2) + \alpha_3(\alpha_3 - 2)] \right\}. \end{aligned} \quad (\text{S27})$$

Minimizing the energy U with respect to α_1 , α_2 , and α_3 then gives

$$\alpha_1 \simeq \frac{c_1}{4 \sin^2 \frac{\theta}{2}} - \frac{c_1^2}{16 \sin^4 \frac{\theta}{2}}, \quad (\text{S28})$$

$$\alpha_{2,3} \simeq \frac{c_{2,3}}{4 \sin^2 \frac{\theta}{2}} + \frac{c_1^2}{16 \sin^4 \frac{\theta}{2}}, \quad (\text{S29})$$

with $c_m = V_m/\mu$ dimensionless materials constants that can be determined from a local-stacking approximation and DFT calculations [50] or from molecular dynamics simulations. Fitting α_m to LAMMPS simulations for TBG yields $c = c_1 \approx 2.2 \times 10^{-5}$ and $c_2/c \approx -0.022$, and $c_3/c \approx -0.013$. This value also gives good agreement between theory and simulations for α_2 and α_3 , as shown by the colored dashed lines in Fig. 3 of the main text.

B. Out-of-plane displacements

The discussion in the main text was focused on the in-plane displacement field. In this section, we present a simple theory for the out-of-plane displacement field.

For an untwisted bilayer with a constant relative shift \mathbf{d} between layers, the interlayer distance is an even periodic function of \mathbf{d} with periods given by the primitive

lattice vectors \mathbf{a}_1 and \mathbf{a}_2 of the monolayer. Moreover, it should be invariant under the symmetries of the monolayer. Hence, we can approximate it as [54]

$$h(\mathbf{d}) = h_0 + 2h_1 \sum_{i=1}^3 \cos(\mathbf{b}_i \cdot \mathbf{d}), \quad (\text{S30})$$

where the sum runs over reciprocal lattice vector of graphene of the first shell that are related by C_{3z} . Here

$$h_0 = \frac{h_{\text{AA}} + 2h_{\text{AB}}}{6}, \quad (\text{S31})$$

$$h_1 = \frac{h_{\text{AA}} - h_{\text{AB}}}{18}, \quad (\text{S32})$$

where h_{AA} and h_{AB} is the interlayer distance for AA [$\mathbf{d} = (0, 0)$] and AB [$\mathbf{d} = (0, a/\sqrt{3})$] stacking, respectively.

For the twisted bilayer, we can view the local lattice structure approximately in terms of an untwisted bilayer with local disregistry given by Eq. (S24). This yields a height profile

$$h(\mathbf{r}) = h_0 + 2h_1 \sum_{i=1}^3 \cos[\mathbf{g}_i \cdot \mathbf{r} + 2\mathbf{b}_i \cdot \mathbf{u}(\mathbf{r})]. \quad (\text{S33})$$

Expanding the right-hand side in lowest order of $|\mathbf{b}_i \cdot \mathbf{u}(\mathbf{r})|$ modifies the Fourier coefficients of the zeroth and first shell as follows

$$h_0 \rightarrow h_0 - 12h_1\alpha_1 = h_0 - \frac{3h_1c_1}{\sin^2 \frac{\theta}{2}}, \quad (\text{S34})$$

$$h_1 \rightarrow h_1(1 - 2\alpha_1) = h_1 \left(1 - \frac{c_1}{2 \sin^2 \frac{\theta}{2}} \right), \quad (\text{S35})$$

and gives rise to second and third shell coefficients

$$h_2 = h_3 = 2h_1\alpha_1 = \frac{h_1c_1}{2 \sin^2 \frac{\theta}{2}}. \quad (\text{S36})$$

Hence the scaling laws for out-of-plane displacements are approximately inherited from the in-plane displacements. Second-order corrections by taking into account terms of order α_1^2 , α_2 , and α_3 give rise to components in $h(\mathbf{r})$ up to the sixth shell. We list them for completion:

$$h_0 \rightarrow h_0 - 6h_1\alpha_1(2 - \alpha_1), \quad (\text{S37})$$

$$h_1 \rightarrow h_1(1 - 2\alpha_1 + 4\alpha_1^2 + 2\alpha_2 + \alpha_3), \quad (\text{S38})$$

$$h_2 = h_1[(2 - 3\alpha_1)\alpha_1 - \alpha_3], \quad (\text{S39})$$

$$h_3 = h_1(2 - \alpha_1)\alpha_1, \quad (\text{S40})$$

$$h_4 = h_5 = \frac{h_1}{2}(5\alpha_1^2 + 2\alpha_2 + \alpha_3), \quad (\text{S41})$$

$$h_6 = h_1(2\alpha_1^2 + \alpha_3). \quad (\text{S42})$$

By fitting these expressions to the LAMMPS data, we find $h_0 \approx 1.6892 \text{ \AA}$ and $h_1 \approx 0.077 \text{ \AA}$. In turn, using Eqs. (S31) and (S32), we obtain $h_{\text{AB}} \approx 3.33 \text{ \AA}$ and

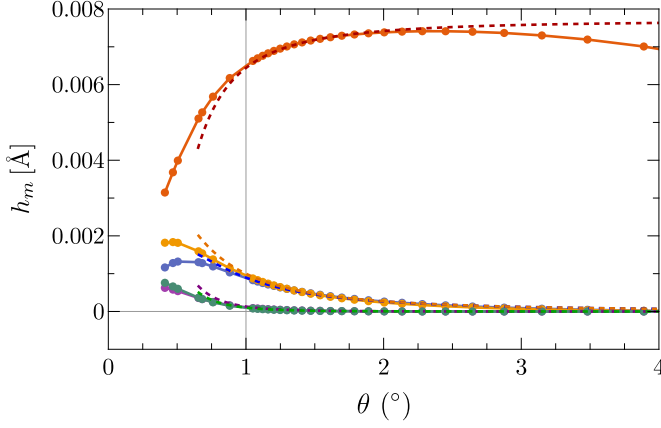


FIG. S3. Fourier components of the relative out-of-plane displacement field. The colored dashed lines are fits to the h_m induced by the in-plane displacement field, as discussed in the text, for $c = 2.2 \times 10^{-5}$.

$h_{AA} \approx 3.47 \text{ \AA}$ which matches the equilibrium interlayer distance for an AB an AA stacked bilayer calculated with the same potentials in LAMMPS. The resulting fits are shown in Fig. S3. Notably, this theory fails for larger twist angles $\theta > 3^\circ$. In this case, the simulations show that it is preferable to reduce the height modulation. A possible explanation is that for larger angles the local stacking varies less slowly on the atomic scale. Hence it is reasonable to assume that conforming the out-of-plane displacement to the local stacking will cost increasing elastic energy as the twist angle increases.

S3. CONTINUUM MODEL FROM SYMMETRY

In this section, we derive the continuum model from symmetry. For small twist angles, the valleys are effectively decoupled, and the low-energy Hamiltonian is given by a Bistritzer-MacDonald (B-M) model [41]

$$H = \sum_{\nu=\pm 1} \int d^2\mathbf{r} \psi_\nu^\dagger(\mathbf{r}) \begin{bmatrix} H_t & T(\mathbf{r}) \\ T^\dagger(\mathbf{r}) & H_b \end{bmatrix} \psi_\nu(\mathbf{r}), \quad (\text{S43})$$

with valley index ν and where $\psi_\nu(\mathbf{r}) = [\psi_{\nu t}(\mathbf{r}), \psi_{\nu b}(\mathbf{r})]^t$ are four-component field operators. In the following, we choose a coordinate system where the x axis of the lies along the zigzag direction of the graphene with primitive lattice vectors $\mathbf{a}_{1,2} = a(\pm 1/2, \sqrt{3}/2)$ where $a = 0.246 \text{ nm}$ is the graphene lattice constant.

A. Intralayer Hamiltonian

The intralayer Hamiltonian can be written as

$$H_{t/b} = \hbar v_F [R_{\mp\theta/2} (-i\nabla - \nu \mathbf{K}_{t/b})] \cdot (\nu \sigma_x, \sigma_y), \quad (\text{S44})$$

where $v_F = 1.05 \times 10^6 \text{ m/s}$ is the monolayer graphene Fermi velocity and $\mathbf{K}_{t/b} = k_\theta (\sqrt{3}/2, \pm 1/2)$ with $k_\theta = 4\pi/3L$ and $L = a/2 \sin(\theta/2)$ the moiré period. Here we have chosen the momentum origin at the center of the moiré Brillouin zone and $\sigma_{x,y}$ are Pauli matrices that act in sublattice space. We do not take into account a symmetry-allowed sublattice potential due to different atomic environments for A and B atoms [58, 61].

The intralayer Hamiltonian can be simplified by a gauge transformation

$$\psi_{\nu l}(\mathbf{r}) \mapsto e^{i\nu \mathbf{K}_l \cdot \mathbf{r}} \psi_{\nu l}(\mathbf{r}), \quad (\text{S45})$$

yielding

$$H_{t/b} = -i\hbar v_F R_{\mp\theta/2} \nabla \cdot (\nu \sigma_x, \sigma_y). \quad (\text{S46})$$

For this gauge choice, the continuum model can be diagonalized by Fourier transform ($l = t, b$)

$$\psi_{\nu l}(\mathbf{r}) = \sum_{\mathbf{k} \in \text{MBZ}} \sum_{\mathbf{g}} e^{i(\mathbf{k} - \nu \mathbf{K}_l - \mathbf{g}) \cdot \mathbf{r}} c_{\nu l}(\mathbf{k} - \mathbf{g}). \quad (\text{S47})$$

B. Moiré coupling

We now consider the interlayer moiré potential in the lowest harmonic. Here we only consider a local moiré potential. Symmetry constraints on nonlocal contributions are discussed in Ref. [53]. In the original gauge, the the lowest moiré harmonic becomes

$$T(\mathbf{r}) = T_1 + T_2 e^{-i\nu \mathbf{g}_1 \cdot \mathbf{r}} + T_3 e^{-i\nu (\mathbf{g}_1 + \mathbf{g}_2) \cdot \mathbf{r}}, \quad (\text{S48})$$

with $\mathbf{g}_1 = -\sqrt{3}k_\theta (1/2, \sqrt{3}/2)$ and $\mathbf{g}_2 = \sqrt{3}k_\theta (1, 0)$ reciprocal lattice vectors of the moiré lattice related by \mathcal{C}_{3z} symmetry. In the new gauge, we have

$$T(\mathbf{r}) \mapsto T(\mathbf{r}) e^{i\nu (\mathbf{K}_b - \mathbf{K}_t) \cdot \mathbf{r}} = \sum_{i=1}^3 T_j e^{i\nu \mathbf{q}_j \cdot \mathbf{r}}, \quad (\text{S49})$$

with $\mathbf{q}_1 = k_\theta (0, -1)$ and $\mathbf{q}_{2,3} = k_\theta (\pm \sqrt{3}/2, 1/2)$. We work in this gauge for the remainder of this section.

The complex 2×2 matrices T_j ($j = 1, 2, 3$) are constrained by the (emergent) symmetries of the moiré lattice that preserve the valley index. The valley-preserving symmetries form the dichromatic group $6'2'2$ also denoted as $D_6(D_3) = D_3 + (D_6 \setminus D_3)\mathcal{T}$ [62] and generated by:

- $\mathcal{C}_{2z}\mathcal{T}$: composition of spinless time reversal \mathcal{T} with a π rotation about the z axis. This operation leaves the layers invariant but exchanges the sublattices;
- \mathcal{C}_{3z} : rotation by $\pm 2\pi/3$ about z . Leaves the sublattices invariant up to a phase factor from rotating the pseudospin;
- \mathcal{C}_{2x} : rotation by π about the x axis. Exchanges both layers and sublattices;

as illustrated in Fig. S1(b).

$\mathcal{C}_{2z}\mathcal{T}$ symmetry

First, we consider $\mathcal{C}_{2z}\mathcal{T}$ symmetry. Its action on the field operators is represented by

$$(\mathcal{C}_{2z}\mathcal{T})\psi_\nu(\mathbf{r})(\mathcal{C}_{2z}\mathcal{T})^{-1} = \tau_0\sigma_x\psi_\nu(-\mathbf{r}), \quad (\text{S50})$$

where τ matrices act in layer space. From $[H, \mathcal{C}_{2z}\mathcal{T}] = 0$ and $\mathcal{T}i\mathcal{T}^{-1} = -i$, we find that the intralayer Hamiltonian is invariant as expected, while the interlayer coupling needs to satisfy

$$T(\mathbf{r}) = \sigma_x T(-\mathbf{r})^* \sigma_x. \quad (\text{S51})$$

$$-i\nabla \cdot (\nu\sigma_x, \sigma_y) \mapsto -iR_{-2\pi/3}\nabla \cdot \left[e^{-i\nu\pi\sigma_z/3} (\nu\sigma_x, \sigma_y) e^{i\nu\pi\sigma_z/3} \right] = -i\nabla \cdot (\nu\sigma_x, \sigma_y). \quad (\text{S54})$$

For the interlayer term, we obtain a relation between the three matrices of each moiré harmonic, reducing the number of real parameters from 12 to 4. Explicitly,

$$T(\mathbf{r}) = e^{-i\nu\pi\sigma_z/3} T(\mathcal{C}_{3z}^{-1}\mathbf{r}) e^{i\nu\pi\sigma_z/3} \quad (\text{S55})$$

$$= \sum_{j=1}^3 e^{-i\nu\pi\sigma_z/3} T_j e^{i\nu\pi\sigma_z/3} e^{i\nu\pi\sigma_z/3} e^{i\mathbf{q}_{j+1}\cdot\mathbf{r}}, \quad (\text{S56})$$

where $\mathbf{q}_4 = \mathbf{q}_1$. We thus require

$$T_{j+1} = e^{-i\nu\pi\sigma_z/3} T_j e^{i\nu\pi\sigma_z/3}. \quad (\text{S57})$$

where $j = 1, 2, 3$ is defined cyclically. Hence,

$$T_1 = a\sigma_0 + id\sigma_z + b\sigma_x + c\sigma_y, \quad (\text{S58})$$

$$T_2 = a\sigma_0 + id\sigma_z + e^{-\frac{i\nu\pi}{3}\sigma_z} (b\sigma_x + c\sigma_y) e^{+\frac{i\nu\pi}{3}\sigma_z}, \quad (\text{S59})$$

$$T_3 = a\sigma_0 + id\sigma_z + e^{+\frac{i\nu\pi}{3}\sigma_z} (b\sigma_x + c\sigma_y) e^{-\frac{i\nu\pi}{3}\sigma_z}. \quad (\text{S60})$$

\mathcal{C}_{2x} symmetry

Lastly we consider \mathcal{C}_{2x} symmetry which exchanges layers and sublattices but leaves the valley invariant. Its action is given by

$$\mathcal{C}_{2x}\psi_\nu(x, y)\mathcal{C}_{2x}^{-1} = \tau_x\sigma_x\psi_\nu(x, -y), \quad (\text{S61})$$

For the first moiré harmonic, taking T_j as a general 2×2 complex matrix:

$$T_j = \sigma_x T_j^* \sigma_x = a_j\sigma_0 + b_j\sigma_x + c_j\sigma_y + id_j\sigma_z, \quad (\text{S52})$$

with $\{a_j, b_j, c_j, d_j\}$ real constants (12 in total). Note that this result holds for any moiré harmonic. For example, the second moiré harmonic lies at distance $2k_\theta$ from the principal Dirac point of a given layer.

\mathcal{C}_{3z} symmetry

While $\mathcal{C}_{2z}\mathcal{T}$ constrains each matrix individually, we now show that \mathcal{C}_{3z} rotation symmetry gives a relation between different T_j matrices. The action on the field operators is given by

$$\mathcal{C}_{3z}\psi_\nu(\mathbf{r})\mathcal{C}_{3z}^{-1} = \tau_0 e^{i\nu\pi\sigma_z/3} \psi_\nu(\mathcal{C}_{3z}\mathbf{r}). \quad (\text{S53})$$

One way to understand the sublattice rotation is that it is required to keep $-i\nabla \cdot (\nu\sigma_x, \sigma_y)$ invariant. Indeed,

which leaves the intralayer Hamiltonian invariant, but gives a constraint on the interlayer coupling. Restricting to the first moiré harmonic, we find

$$T(x, y) = \sigma_x T^\dagger(x, -y) \sigma_x, \quad (\text{S62})$$

or

$$T_1 = \sigma_x T_1^\dagger \sigma_x, \quad T_2 = \sigma_x T_3^\dagger \sigma_x, \quad (\text{S63})$$

which sets $c = 0$.

Finally, we obtain

$$T_j = w_1 e^{i\phi\sigma_z} + w_2 \left[\sigma_x \cos \frac{2\pi j}{3} + \nu\sigma_y \sin \frac{2\pi j}{3} \right] \quad (\text{S64})$$

$$= \begin{pmatrix} w_1 e^{i\phi} & w_2 e^{-i\nu 2\pi j/3} \\ w_2 e^{i\nu 2\pi j/3} & w_1 e^{-i\phi} \end{pmatrix}, \quad (\text{S65})$$

where $a = w_1 \cos \phi$, $d = w_1 \sin \phi$, and $w_2 = b$ are real parameters. The magnetic point group $6'2'2$ thus yields three real parameters for the first moiré harmonic.

C. Discussion

A similar symmetry analysis can be found in Ref. [63] but the phase ϕ of the AA coupling was not considered in this work. At a first glance, one might think that this

phase can be removed by a unitary. Indeed, consider

$$\begin{pmatrix} \psi_{\nu t} \\ \psi_{\nu b} \end{pmatrix} \mapsto e^{i\phi\tau_z\sigma_z/2} \begin{pmatrix} \psi_{\nu t} \\ \psi_{\nu b} \end{pmatrix}, \quad (\text{S66})$$

such that

$$\psi_{\nu t}^\dagger T \psi_{\nu b} \mapsto \psi_{\nu t}^\dagger e^{-i\phi\sigma_z/2} T e^{-i\phi\sigma_z/2} \psi_{\nu b}, \quad (\text{S67})$$

This shows that the phase ϕ of the AA interlayer moiré coupling is equivalent to a rotation of the sublattice pseudospin in the intralayer Hamiltonian. Hence, we can think of ϕ as having a rigid contribution which is negligible in the limit of small twist angles.

D. Pseudo gauge field

In the long-wavelength limit, it is known that strain fields couple to the low-energy electronic degrees of freedom of graphene as effective gauge fields [57, 64]. In particular, shear strain gives rise to a pseudo vector potential $\pm \mathbf{A}_l(\mathbf{r})$ at valley $\mathbf{K}_\pm = (\pm 4\pi/3a, 0)$ for $l = t, b$. For twisted bilayer graphene, we only consider the pseudo gauge field arising from heterostrain. The intralayer Hamiltonian in Eq. (S44) is then modified by replacing $-i\nabla \rightarrow -i\nabla + \nu e \mathbf{A}_l(\mathbf{r})/\hbar$.

In a coordinate system where the x axis lies along the zigzag direction of the original untwisted graphene, the pseudo vector potential is given by [57]

$$\mathbf{A}_t(\mathbf{r}) = \mathbf{A}(\mathbf{r}) = \frac{\sqrt{3}\hbar\beta}{2ea} \begin{pmatrix} u_{t yy} - u_{t xx} \\ u_{t xy} + u_{t yx} \end{pmatrix}, \quad (\text{S70})$$

where $\beta = \frac{a}{\sqrt{3}t_0} \left| \frac{\partial t}{\partial r} \right|_{nn} \approx 2$ is the electron Grüneisen parameter and $-e$ is the electron charge. Here we defined the displacement gradient ($l = t, b$)

$$u_{lij} = \frac{\partial u_{li}}{\partial r_j} + \frac{1}{2} \frac{\partial h_l}{\partial r_i} \frac{\partial h_l}{\partial r_j}, \quad (\text{S71})$$

which is obtained by considering the change in length after a deformation between two points with initial infinitesimal and in-plane separation dr_i [65]. Explicitly, we have $[(dr_i + du_i)^2 + dh^2] - dr_i^2 \equiv 2u_{ij} dr_i dr_j$ where the left-hand side is evaluated up to lowest order in the displacements. To preserve \mathcal{C}_{2x} symmetry, we further have

$$\mathbf{A}_b(x, y) = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix} \mathbf{A}_t(x, -y). \quad (\text{S72})$$

where

$$\begin{aligned} & e^{-i\phi\sigma_z/2} T_j e^{-i\phi\sigma_z/2} \\ & = w_1 \sigma_0 + w_2 \left[\sigma_x \cos \frac{2\pi j}{3} + \nu \sigma_y \sin \frac{2\pi j}{3} \right]. \end{aligned} \quad (\text{S68})$$

However, this unitary affects the intralayer part of the Hamiltonian. Namely,

$$-iR_{\mp\theta/2} \nabla \cdot (\nu \sigma_x, \sigma_y) \mapsto -iR_{\mp\theta/2} \nabla \cdot \left[e^{\mp i\phi\sigma_z/2} (\nu \sigma_x, \sigma_y) e^{\pm i\phi\sigma_z/2} \right] = -iR_{\mp(\theta/2-\phi)} \nabla \cdot (\nu \sigma_x, \sigma_y). \quad (\text{S69})$$

This can be derived from the continuum model or from the transformation of the displacement gradient: $[u_b(x, y)]_{ij} = (\sigma_z)_{ik} [u_t(x, -y)]_{kl} (\sigma_z)_{lj}$. The remaining symmetries of the $6'2'2$ magnetic point group of a single valley, yield, up to a gauge transformation,

$$\mathbf{A}(\mathbf{r}) = \mathbf{A}(-\mathbf{r}) = \mathcal{C}_{3z} \mathbf{A}(\mathcal{C}_{3z}^{-1} \mathbf{r}), \quad (\text{S73})$$

which, together with Eq. (S72), implies

$$B(\mathbf{r}) = -B(-\mathbf{r}) = B(\mathcal{C}_{3z}^{-1} \mathbf{r}), \quad (\text{S74})$$

$$B_b(x, y) = -B_t(x, -y) = B_t(-x, y), \quad (\text{S75})$$

where $B_t(\mathbf{r}) = B(\mathbf{r}) = \hat{z} \cdot \nabla \times \mathbf{A}(\mathbf{r})$.

If we now further neglect the out-of-plane displacements, which is well justified for angles $\theta > 1^\circ$, then $\mathbf{A}_b(\mathbf{r}) = -\mathbf{A}_t(\mathbf{r})$ at every point. Here we used that $\mathbf{u}_b(\mathbf{r}) = -\mathbf{u}_t(\mathbf{r})$ for heterostrain. In this case, the first-shell approximation yields

$$\mathbf{A}(\mathbf{r}) = \frac{3B_0 L^2}{8\pi^2} \sum_{i=1}^3 \hat{z} \times \mathbf{g}_i \cos(\mathbf{g}_i \cdot \mathbf{r}). \quad (\text{S76})$$

Indeed, this is the form that we obtain if we plug in the first-shell approximation for the relative in-plane displacement field given by Eq. (4) of the main text with

$$B_0 = \frac{\hbar \alpha_1 \beta}{e L^2} = \frac{\hbar c \beta}{e a^2} \approx 3 \text{ T}, \quad (\text{S77})$$

using $c = 2.2 \times 10^{-5}$ and $\beta = 2$ and which is independent of the twist angle [58]. Note that we have not taken into account the out-of-plane contribution to the strain tensor. This is justified for twists $\theta > 1^\circ$. In this case, the in-plane contribution to the strain tensor is proportional to $cL/a < 0.001$, while the out-of-plane contribution scales as $(\Delta h/L)^2$ where $\Delta h \sim 0.01 \text{ \AA}$. The corresponding pseudo magnetic field (PMF) becomes

$$B(\mathbf{r}) = -2B_0 \sum_{i=1}^3 \sin(\mathbf{g}_i \cdot \mathbf{r}), \quad (\text{S78})$$

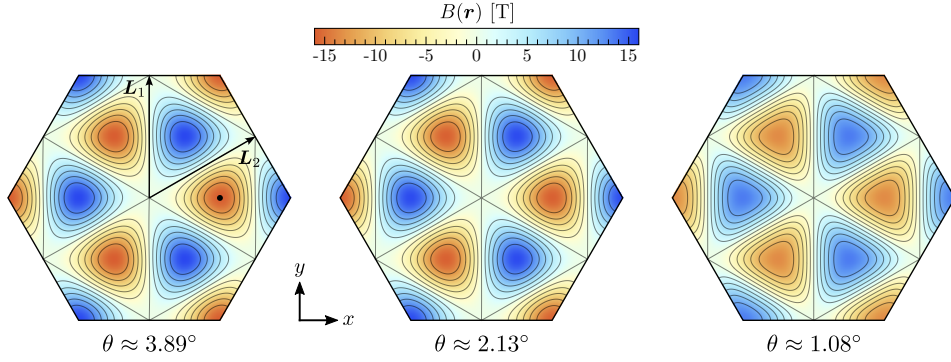


FIG. S4. Pseudo magnetic field from heterostrain calculated from the LAMMPS simulation for TBG for three twist angles.

which vanishes at AA points and has extrema at AB and BA points given by $\pm 3\sqrt{3}B_0 \approx \pm 15.6$ T, respectively. We can further define an effective magnetic length

$$\ell_0 = \sqrt{\frac{\hbar}{eB_0}} = \frac{a}{\sqrt{2\pi c\beta}} \approx 15 \text{ nm}. \quad (\text{S79})$$

We note that the effect of the PMF on the electronic structure is significant only when L/ℓ_0 is large. We show the PMF calculated from the LAMMPS data, including out-of-plane contributions, in Fig. S4.

The value for the strength of the PMF is one order of magnitude smaller than reported in Ref. [42]. This difference is attributed to the fact that the value for $c = V_1/\mu$ in Ref. [42] is about ten times larger. Using molecular dynamics simulations, we estimate $c \sim 10^{-5}$ for TBG. Moreover, in our theory, the PMF does not vary significantly with twist angle for $\theta > 1^\circ$. Deviations arise due to relatively small out-of-plane contributions or in-plane contributions that scale as $c^2/\sin^2(\theta/2)$ and start to become appreciable for $\theta < 1^\circ$. We further find that the PMF actually decreases as the twist angle is reduced below 1° , as shown in Fig. S5. This is similar to Ref. [42] albeit at a smaller twist angle for the same reason as outlined above.

The decrease in the magnitude of the PMF can be understood as follows. First, from symmetry it follows that a PMF induced by in-plane heterostrain vanishes along domain walls separating AB and BA regions:

$$B(x, y) = -B(-x, y), \quad (\text{S80})$$

because \mathcal{C}_{2y} exchanges the valleys, layers, and flips the direction of \hat{z} . Moreover, as the twist angle decreases, domains with nearly uniform AB and BA stacking start to form. While the strain is nonzero in these regions, the PMF is expected to decrease regardless because the microscopic \mathcal{C}_{3z} symmetry is locally restored in these domains. Hence the PMF is pushed entirely to a narrow region surrounding the domain walls.

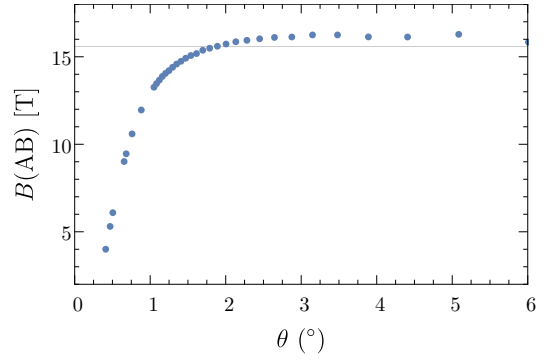


FIG. S5. Pseudo magnetic field from heterostrain calculated with LAMMPS at the Bernal stacking point $\mathbf{r}_{AB} = (L/\sqrt{3}, 0)$, indicated by the black dot in Fig. S4, as a function of twist angle. The vertical line gives the estimate from Eq. (S77).

S4. FERMI VELOCITY

In this section, we obtain an approximate expression for the Fermi velocity by restricting the interlayer moiré coupling in Fourier space. In particular, we retain one copy of the top layer Dirac cone and three moiré copies related by \mathcal{C}_{3z} of the bottom layer [41]. This corresponds to taking the smallest circle with radius $k_\theta = 4\pi/3L$ centered around the principal Dirac point of the top layer, as illustrated in Fig. S6(a). We also define the dimensionless parameters

$$\alpha_{1,2} = \frac{w_{1,2}}{\hbar v_F k_\theta}, \quad \zeta = \frac{2}{\sqrt{3}k_\theta^2 \ell_0^2} = \frac{3\sqrt{3}L^2}{8\pi^2 \ell_0^2}. \quad (\text{S81})$$

Note that it is important to keep track of the rotation of the layers. Here we always consider the case where the top (bottom) layer is rotated by $+\theta/2$ ($-\theta/2$). In this case, the relative displacement field $\mathbf{u}(\mathbf{r})$ due to lattice relaxation with $\mathbf{u}_{t/b} = \pm \mathbf{u}$ should have positive curl at AA regions and negative curl at AB regions. This is because under $\mathbf{u} \rightarrow -\mathbf{u}$ the pseudo magnetic field in a given valley changes sign, leading to the wrong conclusions.

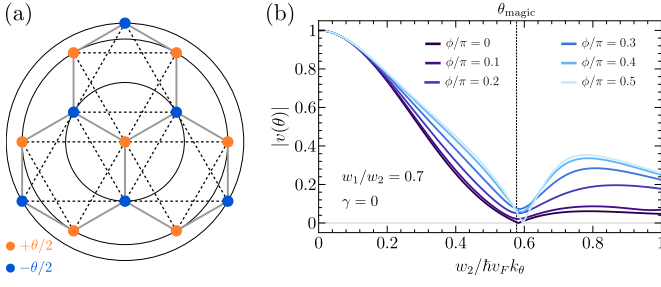


FIG. S6. (a) Moiré replicas of Dirac points at valley K_+ of the top (orange) and bottom (blue) layer. Links between Dirac points of different layers (solid lines) represent interlayer couplings in the first moiré harmonic, while links between the same layer (dashed lines) are coupling induced by the pseudo magnetic field. (b) Converged Fermi velocity for $w_2/w_1 = 0.7$ and $\zeta = 0$ for different values of ϕ as indicated. The horizontal dashed line corresponds to $w_2/\hbar v_F k_\theta = 1/\sqrt{3}$.

In this approximation, the Bloch Hamiltonian for valley K_+ in dimensionless units becomes

$$h(\mathbf{k}) = \begin{bmatrix} \mathbf{k} \cdot \boldsymbol{\sigma} & T_1 & T_2 & T_3 \\ T_1^\dagger & (\mathbf{k} - \mathbf{q}_1) \cdot \boldsymbol{\sigma} & -\zeta \mathbf{A}_1 \cdot \boldsymbol{\sigma} & -\zeta \mathbf{A}_3 \cdot \boldsymbol{\sigma} \\ T_2^\dagger & -\zeta \mathbf{A}_1 \cdot \boldsymbol{\sigma} & (\mathbf{k} - \mathbf{q}_2) \cdot \boldsymbol{\sigma} & -\zeta \mathbf{A}_2 \cdot \boldsymbol{\sigma} \\ T_3^\dagger & -\zeta \mathbf{A}_3 \cdot \boldsymbol{\sigma} & -\zeta \mathbf{A}_2 \cdot \boldsymbol{\sigma} & (\mathbf{k} - \mathbf{q}_3) \cdot \boldsymbol{\sigma} \end{bmatrix} \quad (\text{S82})$$

$$\equiv \begin{bmatrix} 0 & T_1 & T_2 & T_3 \\ T_1^\dagger & -h_1 & -A_{12} & -A_{13} \\ T_2^\dagger & -A_{21} & -h_2 & -A_{23} \\ T_3^\dagger & -A_{31} & -A_{32} & -h_3 \end{bmatrix} + \begin{bmatrix} \mathbf{k} \cdot \boldsymbol{\sigma} & 0 & 0 & 0 \\ 0 & \mathbf{k} \cdot \boldsymbol{\sigma} & 0 & 0 \\ 0 & 0 & \mathbf{k} \cdot \boldsymbol{\sigma} & 0 \\ 0 & 0 & 0 & \mathbf{k} \cdot \boldsymbol{\sigma} \end{bmatrix}, \quad (\text{S83})$$

with $\mathbf{q}_1 = (0, -1)$, $\mathbf{q}_{2,3} = (\pm\sqrt{3}/2, 1/2)$, and $\mathbf{A}_i = \hat{z} \times \hat{y}_i$ ($i = 1, 2, 3$). Here we moved the momentum origin to the principal Dirac point of the top layer and defined $h_i = \mathbf{q}_i \cdot \boldsymbol{\sigma}$ and

$$A_{ij} = \zeta \begin{pmatrix} 0 & \mathbf{A}_1 \cdot \boldsymbol{\sigma} & \mathbf{A}_3 \cdot \boldsymbol{\sigma} \\ \mathbf{A}_1 \cdot \boldsymbol{\sigma} & 0 & \mathbf{A}_2 \cdot \boldsymbol{\sigma} \\ \mathbf{A}_3 \cdot \boldsymbol{\sigma} & \mathbf{A}_2 \cdot \boldsymbol{\sigma} & 0 \end{pmatrix}. \quad (\text{S84})$$

Following Ref. [41], the Fermi velocity is obtained from perturbation theory in $|\mathbf{k}|$. Hence, we first need to diagonalize $h(\mathbf{k})$ at the origin. To this end, we first write the

wave function at $|\mathbf{k}| = 0$ as $\Psi = (\psi_0, \psi_1, \psi_2, \psi_3)^t$. Here ψ_0 corresponds to the top layer and ψ_i ($i = 1, 2, 3$) are the components of the bottom layer at momentum \mathbf{q}_i . The eigenvalue equation can then be written as

$$\sum_{i=1}^3 T_i \psi_i = \varepsilon \psi_0, \quad (\text{S85})$$

$$T_i^\dagger \psi_0 - \sum_{j=1}^3 (h_i \delta_{ij} + A_{ij}) \psi_j = \varepsilon \psi_i. \quad (\text{S86})$$

Solving Eq. (S86) for the components of the bottom layer and plugging this into Eq. (S85) yields

$$\begin{pmatrix} T_1 & T_2 & T_3 \end{pmatrix} \begin{pmatrix} \varepsilon + h_1 & A_{12} & A_{13} \\ A_{21} & \varepsilon + h_2 & A_{23} \\ A_{31} & A_{32} & \varepsilon + h_3 \end{pmatrix}^{-1} \begin{pmatrix} T_1^\dagger \\ T_2^\dagger \\ T_3^\dagger \end{pmatrix} \psi_0 = \varepsilon \psi_0. \quad (\text{S87})$$

There are two types of solutions. Either ψ_0 is nonzero with doubly-degenerate eigenvalues and solutions $\psi_0^{(1)} = (1, 0)^t$ and $\psi_0^{(2)} = (0, 1)^t$, or otherwise ψ_0 vanishes. In the former, the components from the second layer are obtained from

Eq. (S86). We then find that the matrix on the left-hand side of Eq. (S87) is proportional to the unit matrix, and the energies are given by the roots of a depressed cubic:

$$\varepsilon [(\varepsilon + \zeta + 1)(\varepsilon - \zeta - 1) - 3(w_1^2 + w_2^2)] - 6w_1w_2(1 + \zeta)\sin\phi = 0, \quad (\text{S88})$$

where ϕ is the phase of the AA coupling. However, this equation only yields six eigenvalues. The remaining two eigenvalues are solutions with $\psi_0 = (0, 0)^t$. We henceforth focus on solutions $\Psi_{1,2}$ with nonzero ψ_0 and the smallest $|\varepsilon|$. The Fermi velocity is obtained by projecting $h(\mathbf{k})$ on these eigenstates. In the basis $\{\psi_0^{(1)}, \psi_0^{(2)}\}$ we have

$$\begin{pmatrix} 0 & v \\ v^* & 0 \end{pmatrix} = \frac{\sigma_x + \begin{pmatrix} T_1 & T_2 & T_3 \end{pmatrix} \begin{pmatrix} \varepsilon + h_1 & A_{12} & A_{13} \\ A_{21} & \varepsilon + h_2 & A_{23} \\ A_{31} & A_{32} & \varepsilon + h_3 \end{pmatrix}^{-1} \begin{pmatrix} \sigma_x & 0 & 0 \\ 0 & \sigma_x & 0 \\ 0 & 0 & \sigma_x \end{pmatrix} \begin{pmatrix} \varepsilon + h_1 & A_{12} & A_{13} \\ A_{21} & \varepsilon + h_2 & A_{23} \\ A_{31} & A_{32} & \varepsilon + h_3 \end{pmatrix}^{-1} \begin{pmatrix} T_1^\dagger \\ T_2^\dagger \\ T_3^\dagger \end{pmatrix}}{1 + \psi_0^{(1)\dagger} \begin{pmatrix} T_1 & T_2 & T_3 \end{pmatrix} \begin{pmatrix} \varepsilon + h_1 & A_{12} & A_{13} \\ A_{21} & \varepsilon + h_2 & A_{23} \\ A_{31} & A_{32} & \varepsilon + h_3 \end{pmatrix}^{-2} \begin{pmatrix} T_1^\dagger \\ T_2^\dagger \\ T_3^\dagger \end{pmatrix} \psi_0^{(1)}}, \quad (\text{S89})$$

with v in units of v_F . In the special case $\phi = 0$, there is a zero-energy solution $\varepsilon = 0$ and we find

$$v(\theta) = \frac{(1 + \zeta)^2 - 3\alpha_2^2}{(1 + \zeta)^2 + 3\alpha_1^2 + 3\alpha_2^2}, \quad (\text{S90})$$

which vanishes for $\alpha_2 = (1 + \zeta)/\sqrt{3}$. Hence, using that $k_\theta \approx \theta 4\pi/3a$, we obtain

$$\frac{16\pi^2}{3\sqrt{3}}\theta^2 - \frac{4\pi w_2 a}{\hbar v_F}\theta + \left(\frac{a}{\ell_0}\right)^2 = 0, \quad (\text{S91})$$

which has one physical solution given by

$$\theta_{\text{magic}} = \frac{3\sqrt{3}w_2 a}{8\pi\hbar v_F} + \frac{\sqrt{3}}{8\pi} \sqrt{\left(\frac{3aw_2}{\hbar v_F}\right)^2 - \frac{4\sqrt{3}}{\ell_0^2}} \quad (\text{S92})$$

$$= \frac{3\sqrt{3}w_2 a}{4\pi\hbar v_F} - \frac{\hbar v_F a}{4\pi w_2 \ell_0^2} + \mathcal{O}(a^4/\ell_0^4). \quad (\text{S93})$$

Thus the pseudo magnetic field merely shifts the magic angle to a lower value. However, when ϕ is nonzero, we find numerically that there is no angle at which v vanishes, as shown in Fig. S6(b). Instead the magnitude of the velocity at θ_{magic} becomes finite and is approximately

given by

$$v_{\text{min}} = \frac{4w_1^2 w_2^2 \phi}{(w_1^2 + 2w_2^2)^2}. \quad (\text{S94})$$

S5. MOIRÉ POTENTIAL

In this section, we estimate the effect of lattice relaxation on the moiré potential. For the rigid case, the moiré potentials for tunnelings between equal and opposite sublattices are related by a translation such that $w_1 = w_2$. However, lattice relaxation breaks this symmetry leading to a difference in the moiré potentials which varies as a function of twist angle. Below, we use the local-stacking approximation to obtain an approximate expression for w_1 and w_2 as a function of twist angle using our theory for lattice relaxation valid for twist angles $\theta \gtrsim 1^\circ$.

A. Local-stacking approximation

We calculate the moiré potential from the local-stacking approximation [54, 66]. In this approximation, we first consider the interlayer matrix element between two layers with a constant relative shift \mathbf{d} . Expanding the Bloch states in a basis of atomic orbitals, we find

$$T_{\sigma\sigma'}(\mathbf{k}, \mathbf{d}) = \langle \mathbf{k}\sigma | H | \mathbf{k}\sigma' \rangle = \frac{1}{N} \sum_{\mathbf{R}_\sigma} \sum_{\mathbf{R}_{\sigma'}} e^{-i\mathbf{k}\cdot(\mathbf{R}_\sigma - \mathbf{R}_{\sigma'})} \langle \mathbf{R}_\sigma | H | \mathbf{R}_{\sigma'} \rangle \quad (\text{S95})$$

$$= \frac{1}{N} \sum_{\mathbf{R}_\sigma} \sum_{\mathbf{R}_{\sigma'}} e^{-i\mathbf{k}\cdot(\mathbf{R}_\sigma - \mathbf{R}_{\sigma'})} t_\perp(\mathbf{R}_\sigma - \mathbf{R}_{\sigma'}) \quad (\text{S96})$$

$$= \sum_{\mathbf{R}} e^{-i\mathbf{k}\cdot(\mathbf{R} + \delta_{\sigma\sigma'} + \mathbf{d})} t_\perp[\mathbf{R} + \delta_{\sigma\sigma'} + \mathbf{d} + h(\mathbf{d})\hat{z}] \quad (\text{S97})$$

where we used the two-center approximation in the second to last step and the positions of atoms in the top and bottom layer are given by

$$\begin{aligned}\mathbf{R}_\sigma &= \mathbf{R} + \boldsymbol{\delta}_\sigma + \mathbf{d} + h(\mathbf{d})\hat{z}, \\ \mathbf{R}_{\sigma'} &= \mathbf{R} + \boldsymbol{\delta}_{\sigma'},\end{aligned}\quad (\text{S98})$$

respectively. Here $\mathbf{R} = n_1\mathbf{a}_1 + n_2\mathbf{a}_2$ is a lattice vector of monolayer graphene, $\boldsymbol{\delta}_\sigma$ is the sublattice position, and $\boldsymbol{\delta}_{\sigma\sigma'} = \boldsymbol{\delta}_\sigma - \boldsymbol{\delta}_{\sigma'}$. In the local-stacking approximation, the moiré potential is obtained by replacing the constant shift \mathbf{d} with the local atomic registry [66]

$$\mathbf{d}(\mathbf{r}) = 2 \sin(\theta/2) \hat{z} \times \mathbf{r} + 2\mathbf{u}(\mathbf{r}), \quad (\text{S100})$$

and setting $\mathbf{k} = \mathbf{K}_\pm$. We obtain

$$T_{\sigma\sigma'}(\mathbf{K}_\pm, \mathbf{r}) = \sum_{\mathbf{R}} e^{-i\mathbf{K}_\pm \cdot [\mathbf{R} + \boldsymbol{\delta}_{\sigma\sigma'} + \mathbf{d}(\mathbf{r})]} t_\perp [\mathbf{R} + \boldsymbol{\delta}_{\sigma\sigma'} + \mathbf{d}(\mathbf{r}) + h(\mathbf{r})\hat{z}] = \sum_{\mathbf{g}} \check{T}_{\sigma\sigma'}(\mathbf{K}_\pm, \mathbf{g}) e^{i\mathbf{g} \cdot \mathbf{r}}, \quad (\text{S101})$$

where the sum runs over moiré reciprocal vectors. The coefficients are given by

$$\check{T}_{\sigma\sigma'}(\mathbf{K}_\pm, \mathbf{g}) = \frac{1}{A} \sum_{\mathbf{R}} \int_{\text{moiré cell}} d^2\mathbf{r} e^{-i\mathbf{g} \cdot \mathbf{r}} e^{-i\mathbf{K}_\pm \cdot [\mathbf{R} + \boldsymbol{\delta}_{\sigma\sigma'} + \mathbf{d}(\mathbf{r})]} t_\perp [\mathbf{R} + \boldsymbol{\delta}_{\sigma\sigma'} + \mathbf{d}(\mathbf{r}) + h(\mathbf{r})\hat{z}] \quad (\text{S102})$$

$$= \frac{1}{A} \int d^2\mathbf{r} e^{-i\mathbf{g} \cdot \mathbf{r}} e^{-i\mathbf{K}_\pm \cdot \left[2 \sin \frac{\theta}{2} \hat{z} \times \mathbf{r} + \boldsymbol{\delta}_{\sigma\sigma'} + 2\mathbf{u}(\mathbf{r}) \right]} t_\perp \left[2 \sin \frac{\theta}{2} \hat{z} \times \mathbf{r} + \boldsymbol{\delta}_{\sigma\sigma'} + 2\mathbf{u}(\mathbf{r}) + h(\mathbf{r})\hat{z} \right] \quad (\text{S103})$$

$$= \frac{e^{i\mathbf{b} \cdot \boldsymbol{\delta}_{\sigma\sigma'}}}{A_g} \int d^2\mathbf{r} e^{-i\mathbf{g} \cdot \mathbf{r}} e^{-i\mathbf{K}_\pm \cdot [\hat{z} \times \mathbf{r} + 2\mathbf{u}(\mathbf{r}')] } t_\perp [\hat{z} \times \mathbf{r} + 2\mathbf{u}(\mathbf{r}') + h(\mathbf{r}')\hat{z}], \quad (\text{S104})$$

where we used that $\mathbf{R} \times \hat{z}/2 \sin(\theta/2)$ is a moiré lattice vector, $\mathbf{b} = \hat{z} \times \mathbf{g}/2 \sin(\theta/2)$ is a graphene reciprocal lattice vector, $\mathbf{r}' = (\mathbf{r} + \hat{z} \times \boldsymbol{\delta}_{\sigma\sigma'})/2 \sin(\theta/2)$, and $A_g = \sqrt{3}a^2/2$ is the graphene unit cell area.

$h(-\mathbf{r}) = h(\mathbf{r})$. Hence we find

$$\check{T}_{\sigma\sigma'}(\mathbf{K}_\pm, \mathbf{g}) = \check{T}_{\sigma'\sigma}(\mathbf{K}_\mp, -\mathbf{g}) \quad (\text{S105})$$

$$= \left[\check{T}_{\sigma'\sigma}(\mathbf{K}_\pm, \mathbf{g}) \right]^*, \quad (\text{S106})$$

such that $\check{T}_{AA}(\mathbf{K}_\pm, \mathbf{g})$ is always real in the local-stacking approximation when \mathcal{C}_{2z} is conserved.

We now find an expression for the interlayer tunneling amplitudes using our theory for lattice relaxation in TBG. For simplicity, we neglect the out-of-plane modulation as it is small compared to the in-plane displacements. To lowest order in the in-plane displacement field,

Relationships between different coefficients can be obtained from symmetry. For example, since \mathcal{C}_{2z} symmetry is preserved in TBG, we have $\mathbf{u}(-\mathbf{r}) = -\mathbf{u}(\mathbf{r})$ and

$$e^{-i\mathbf{K}_\pm \cdot [\hat{z} \times \mathbf{r} + 2\mathbf{u}(\mathbf{r}')] } t_\perp [\hat{z} \times \mathbf{r} + 2\mathbf{u}(\mathbf{r}') + h(\mathbf{r}')\hat{z}] \quad (\text{S107})$$

$$\simeq e^{-i\mathbf{K}_\pm \cdot \hat{z} \times \mathbf{r}} \left\{ t_\perp (\hat{z} \times \mathbf{r} + h_0\hat{z}) + 2\mathbf{u}(\mathbf{r}') \cdot \left[-i\mathbf{K}_\pm t_\perp (\hat{z} \times \mathbf{r} + h_0\hat{z}) + \frac{\partial t_\perp(\mathbf{v} + h_0\hat{z})}{\partial \mathbf{v}} \Big|_{\mathbf{v}=\hat{z} \times \mathbf{r}} \right] \right\}. \quad (\text{S108})$$

With this expansion and using the parameterization for the interlayer tunneling from Ref. [66], we find that

$$w_1 = \check{T}_{AA}(\mathbf{K}_\pm, \mathbf{0}) \simeq w_0 - \frac{0.94V_{pp\sigma}^0 c}{4 \sin^2 \frac{\theta}{2}}, \quad (\text{S109})$$

$$w_2 = \check{T}_{AB}(\mathbf{K}_\pm, \mathbf{0}) \simeq w_0 + \frac{0.94V_{pp\sigma}^0 c}{8 \sin^2 \frac{\theta}{2}}, \quad (\text{S110})$$

with $c = V_1/\mu \approx 2.2 \times 10^{-5}$.

B. First shell approximation with the relaxation parameter ϕ

As we show in S65, the relaxation parameter ϕ is allowed by symmetry. Previous numerical results from Ref. [43] showed that ϕ has a small non-zero value and that higher-order shells beyond the first shell become more pronounced with relaxation. Therefore, both effects contribute to the reconstruction of the electronic spectrum of TBG. However, in this work, we introduce an alternative approach (see Equation 9 in the main text) that employs only the first shell while using ϕ to encode information about all other relaxation effects, which, in principle, could be captured only when higher-order shells are considered. This proposed model can, to an excellent degree, match the spectrum of the relaxed tight-binding TBG electronic model.

Figure S7 demonstrates the validation of both the low and high-energy features of the proposed effective relaxed electronic continuum model against tight-binding calculations that include atomic relaxation [55, 56]. The relaxation parameter ϕ aids in reproducing the relaxed tight-binding energy spectrum, and the electron-hole asymmetry is accurately captured. The excellent agreement with the tight-binding calculations indicates that our proposed effective relaxed model can serve as a robust non-interacting Hamiltonian, upon which interacting theories could be developed.

S6. MOLECULAR DYNAMICS SIMULATIONS

In the context of small twist angles where the moiré structure is notably large and contains a substantial number of atoms within the supercell, conducting first-principle calculations proves to be prohibitively expensive. In this regime, we calculate atomic relaxation with molecular dynamics simulations using the Large-scale Atomic/Molecular Massively Parallel Simulator (LAMMPS) code which employs classical interatomic force field models [67]. While these molecular dynamics simulations allow for larger supercell sizes, they have inherent limitations on accuracy over the choice of interatomic potentials. It is our experience that while different interatomic potentials might give slightly different numerical values for the scaling factor c , their qualitative behavior and symmetry properties are identical. For twisted bilayer graphene, we use the Drip potential for interlayer interactions and the REBO potential for intralayer interactions [68–70]. For twisted WSe₂ we use the KC potential for interlayer interactions and the SW potential for intralayer interactions with SW/mod style [71, 72]. For this work, we perform relaxation calculations for commensurate twist angles ranging from $\theta = 0.05^\circ$ to $\theta = 20^\circ$. The smallest twist angles correspond to moiré cells with over 4.3 million atoms. Despite the large number of atoms in the simulation cell, the geometry optimizations remain computationally tractable due to the low cost of the classical potentials.

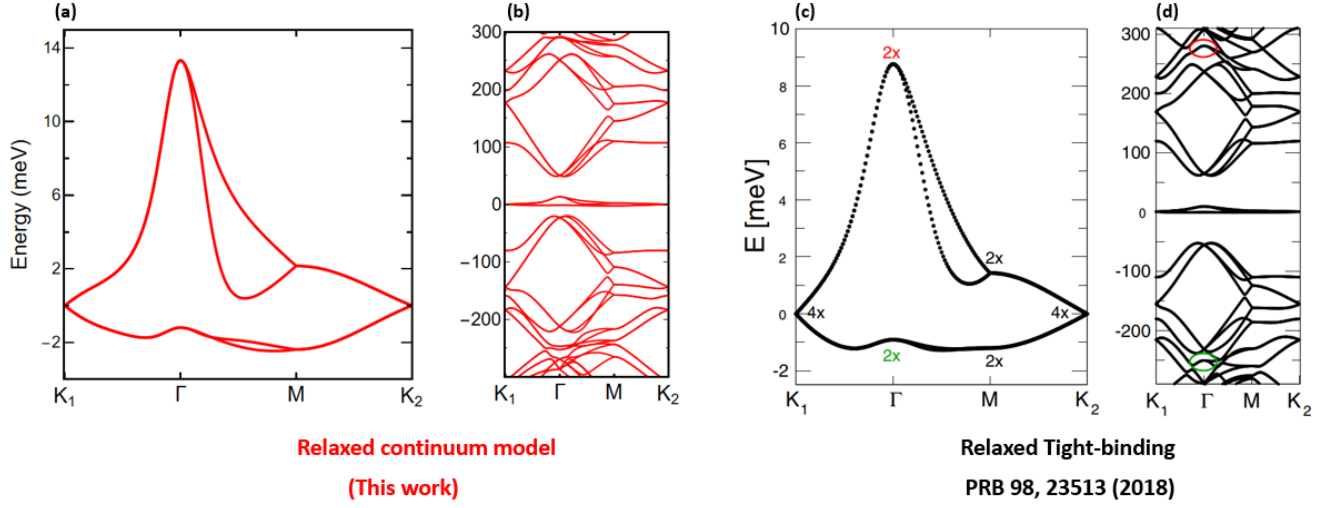


FIG. S7. Validating the effective first shell approximation with the ϕ parameter against relaxed tight-binding calculations. (a) Low-energy bands of the proposed continuum model for $\theta = 1.08^\circ$. (b) Zoom-out view of the band structure of the effective model showing additional bands around charge neutrality points. (c, d) Corresponding tight-binding results to (a) and (b) taken from [55]. It is evident that the effective continuum model captures not only the low-energy bands but also the high-energy features of the spectrum. Similar agreement is achieved in comparison with the results of [56] (not shown here).